

M62501P/FP

PWM IC for the Synchronized Deflection System Control

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General Description

The M62501P/FP is a controller for a deflection system of CRT display monitors. It performs a stable PWM control over a wide fluctuation of external signals, thanks to the built-in trigger mode oscillator. The IC is suitable for an application to a high voltage drive of monitors because of its following circuits and functions;

- low voltage malfunction protection circuit,
- over or under voltage protection circuit for a control line,
- soft-start function.

It is also applicable to a horizontal output correction.

Features

- PWM output synchronized with external signals
- Wide pulse width modulation control frequency 15 kHz to 150 kHz
- Soft start function
- The under voltage output malfunction protection circuit

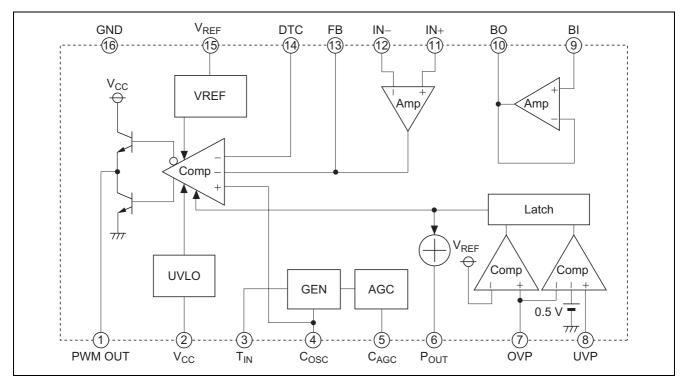
start $V_{CC} > 9 V$

- stop $V_{CC} < 6 V$
- Built-in over voltage protection (OVP) and under voltage protection (UVP) control

Application

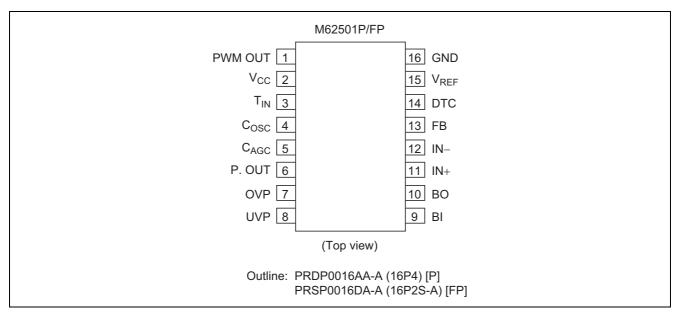
CRT display monitor

Block Diagram





Pin Arrangement



Terminal Number and The Facility

PIN No.	Symbol	Functional Description
1	PWM OUT	PWM output
2	V _{cc}	Power supply
3	T _{IN}	Trigger input
4	C _{OSC}	Setting oscillating frequency
5	C _{AGC}	AGC setting
6	P.OUT	Error signal output
7	OVP	Input of over voltage protection
8	UVP	Input of under voltage protection
9	BI	Positive input of buffer Amp.
10	BO	Output of buffer Amp.
11	IN+	Positive input of Op-Amp.
12	IN-	Negative input of Op-Amp.
13	FB	Output of Op-Amp.
14	DTC	Dead time control (Soft start function)
15	V _{REF}	Output of reference voltage (5 V)
16	GND	Ground

Absolute Maximum Ratings

			(Ta =	$= 25^{\circ}$ C, unle	ess otherwise noted
Item	Symbol	Ratings		Unit	Conditions
Supply voltage	V _{CC}	15		V	
Output voltage	V _{OUT}	1:	5	V	
Output current	I _{OUT}	±100		mA	
Error amplifier input common mode voltage	VICM	-0.3 to V _{CC}		V	
Error amplifier differential input voltage	V _{ID}	V _{CC}		V	
Power dissipation	Pd	Р	FP	mW	
		1200	650		
Thermal derating	Κθ	Р	FP	mW/°C	Ta≥25°C
		9.6	5.2		
Operating temperature	Topr	-20 to +75		°C	
Storage temperature	Tstg	-40 to +150		°C	

2500



Electrical Characteristics

		Symbol	Limits				
Block	Item		Min	Max	Unit	Test Conditions	
All device	Range of power supply	Vcc	V _{CC} OFF		14	V	
	Circuit current	Icc		20		mA	Output off mode
Reference	Reference voltage	V_{REF}	4.80	5.00	5.20	V	I _{REF} = –5 mA
voltage	Input regulation	Reg-in		1.0	10	mV	$V_{CC} = 7$ to 14 V
section							$I_{REF} = -5 \text{ mA}$
	Load regulation	Reg-L	—	2.0	20	mV	$I_{REF} = 0$ to -5 mA
	Reference voltage thermal	TC _{VREF}	—	0.01		%/°C	
	coefficient						
	Maximum reference current	$I_{\text{REF MAX}}$		-30		mA	
	Short-circuit current	ls	—	-30	_	mA	
Error Amp. Buffer Amp.	Input offset voltage	V _{IO}	—	—	7	mV	
	Input bias current	l _{lb}	-100	—	_	nA	
	Input offset current	I _{IO}	-100		100	nA	
	Common mode input voltage range	VICM	-0.3	_	$V_{CC}-2$	V	
	Open loop transmission gain	AV	70	110		dB	
	Slew rate	SR		4		V/µs	
	Output voltage range	V _{OR}	0.3		V _{REF} – 1.5	V	
	Output sink current	Isink	10			mA	
	Output source current	Isource			-10	mA	
	Input bias current	lb	-20			nA	
	Slew rate	SR		4		V/µs	
	Output voltage	Vor	0.3		$V_{CC}-2.5$	V	
	Output sink current	Isink	2			mA	
	Output source current	Isource			-10	mA	
Oscillator	Oscillation frequency	f _{OSC}	15		150	kHz	
	The oscillator waveform bound voltage	V _{OSC H}	—	3.5		V	
	The oscillator waveform lower limit voltage	V _{OSC L}		1.5		V	
	High level of TIN	V _{TIN H}	2.5		Vcc	V	
	Low level of TIN	V _{TIN L}	_		1.0	V	
PWM output	Output saturation voltage L	V _{sat L}	_	0.7	1.4	V	l _o = 100 mA
section	Output saturation voltage H	V _{sat H}	9.5	10.5	_	V	I _O = -100 mA
UVLO	ON threshold voltage	V _{TH ON}	8.0	9.0	10.0	V	
section	OFF threshold voltage	VTH OFF	5.4	6.0	6.6	V	
OVP section	OVP terminal threshold voltage	V _{TH OVP}	4.75	5.00	5.25	V	
	OVP terminal input current	I _{IN OVP}			1.0	μA	
UVP section	Input offset voltage	V _{UVPO}			7	mV	
	UVP terminal input current	I _{IN UVP}		_	1.0	μA	
P.OUT	Output saturation voltage	Vsat		_	0.4	V	I _{PO} = 10 mA
section	Output leakage current	IL	<u> </u>		1.0	μA	V _{PO} = 12 V



Terminal		
No.	Symbol	Function and Terminal Circumscription Circuitry
1	PWM OUT	 PWM output terminal The PWM output synchronized with the T_{IN} input. Output "H" level = 10.5 V typ (The output load current: -100 mA, V_{CC} = 12 V) Output "L" level = 0.7 V typ (The output load current: +100 mA, V_{CC} = 12 V)
2	V _{CC}	Power supply terminal
3	T _{IN}	 Trigger input terminal Frequency range 15 kHz to 150 kHz It takes in a start edge.
		T _{IN} input waveform Min 1.0 V (6) GND
4	Cosc	Cosc terminal
-	Cose	 It generates a saw wave by connecting capacitor between 4-pin and GND. Recommended capacitor value is 1000 pF.
5	C _{AGC}	C _{AGC} terminal • It sets up sensitivity of AGC by connecting capacitor between 5-pin and GND. • Recommended capacitor value is 1 μF. V _{REF} 15 C _{OSC} 4 C _{OSC} 4 GND 16

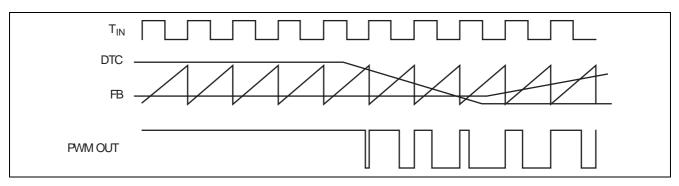
Terminal Functional Description and Equivalent Circuit

Terminal		
No.	Symbol	Function and Terminal Circumscription Circuitry
6	P.OUT	 The abnormal state detection output terminal The output becomes "H" from "L" when an abnormality is detected in the OVP or UVP terminal. Then the PWM output terminal becomes "H" settlement, too. Do OFF of power supply (V_{CC}) to remove latch of abnormal state. In abnormal state detection; Output "H" level = 10.5 V typ (The output load current: no-load, V_{CC} = 12 V) Output "L" level = 1.5 V typ (The output load current: -1 mA, V_{CC} = 12 V) In normal state ; Output "L" level = 0.4 V typ (The output load current: +10 mA, V_{CC} = 12 V)
7	OVP	Over voltage protection of the control line (OVP) Setting terminal voltage; GND ≤ V_{OVP} < V_{REF}
8	UVP	Under voltage protection of the control line (UVP) • Setting terminal voltage; GND $\leq V_{UVP} < V_{OVP}$ Vace 2 VREF (15 OVP (
9	BI	
10	BO	The input terminal of a buffer Amp. (BI) The output terminal of a buffer Amp. (BO) V_{CC} (2) U_{CC} (2) U_{CC} (2) U_{CC} (1) U_{CC} (1) U_{CC} (2) U_{CC} (1) U_{CC} (1) U_{CC} (2) U_{CC} (1) U_{CC} (1) U_{CC} (2) U_{CC} (1) U_{CC} (2) U_{CC} (2) U_{CC} (1) U_{CC} (2) U_{CC} (2) U_{CC} (1) U_{CC} (2) U_{CC} (2)

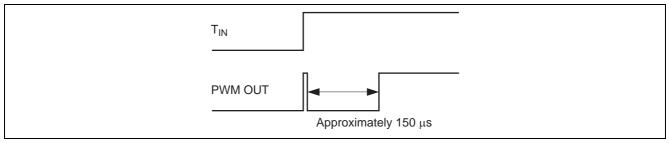
Terminal		
No.	Symbol	Function and Terminal Circumscription Circuitry
11	IN+	Positive input terminal of an Op-Amp. (IN+) V _{CC} (2)
12	IN–	Negative input terminal of an Op-Amp. (IN–)
13	FB	Output terminal of an Op-Amp. (FB)
14	DTC	Dead time control terminal (DTC)
		It can do soft start during power-on under keeping time constant.
		PWM comparator section
15	V _{REF}	Reference voltage terminal • 5 V output voltage (The terminal can begin to take outside connected load 5 mA.) V _{CC} (2) (15) V _{REI} (15) V _{REI}
16	GND	Ground terminal
10		

Timing Chart

PWM OUT ON Duty is fixed in the voltage of higher one between DTC terminal and FB terminal voltage.



• Waveform at "H" was taken from "L", and having put T_{IN} up. (PWM output is fixed in "H", too when fix T_{IN} terminal in "H")

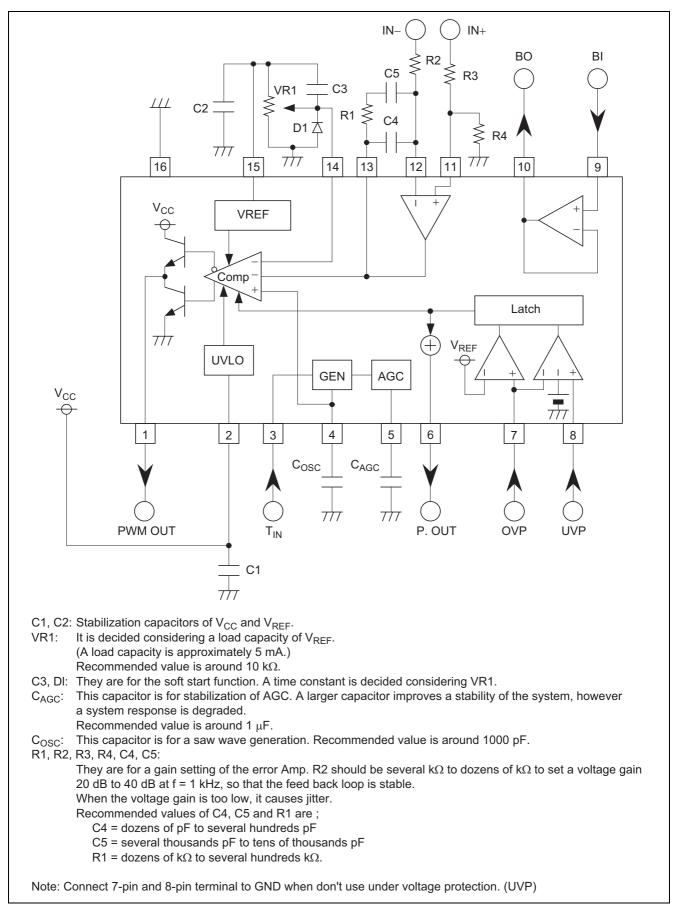


• Waveform at "L" was taken from "H", and having put T_{IN} up. (PWM output is fixed in "L", too when fix T_{IN} terminal in "L")

T _{IN}	
PWM	

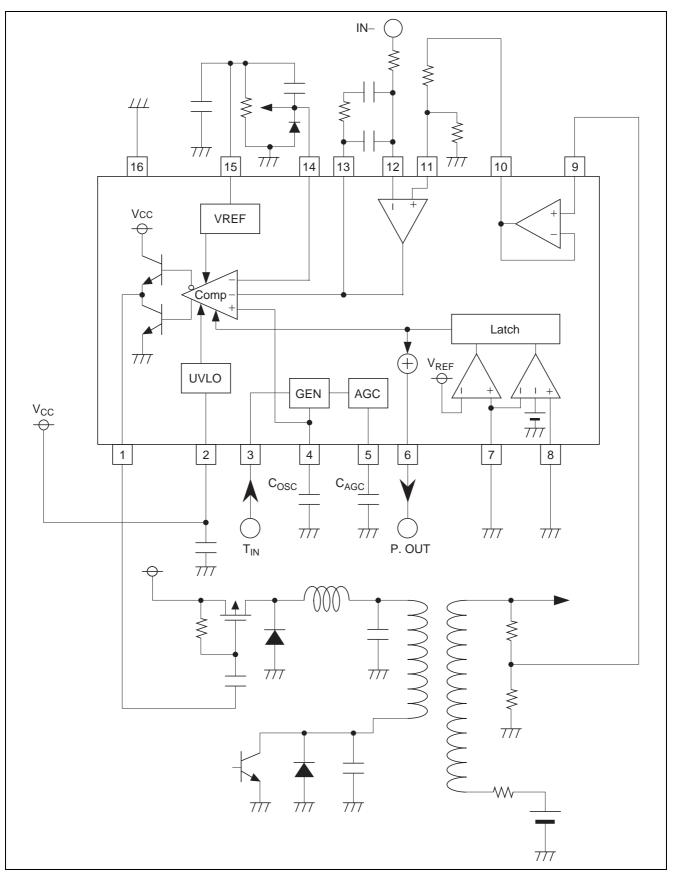


M62501 Application

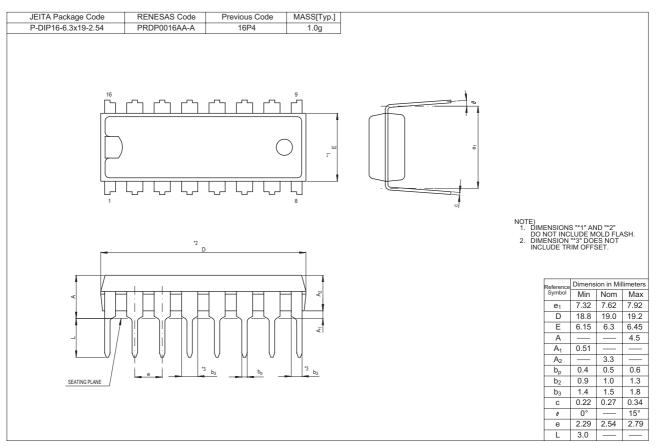


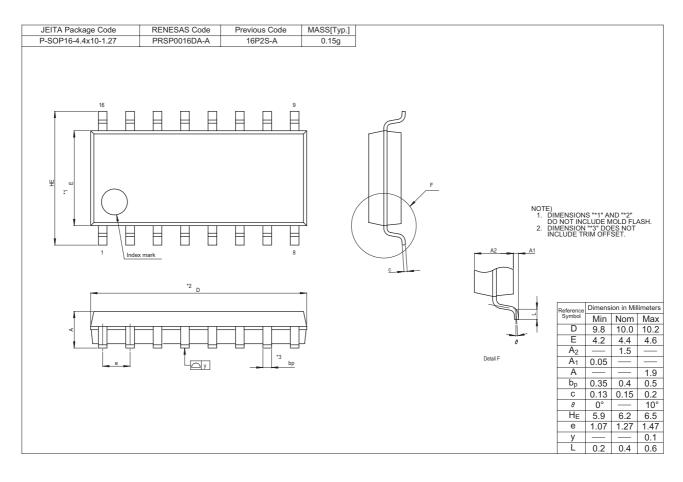


Example of Application Circuit



Package Dimensions







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